74LVC1G38

2-input NAND gate; open drain

Rev. 9 — 18 May 2021

Product data sheet

1. General description

The 74LVC1G38 is a single 2-input NAND gate with open-drain output. Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in mixed 3.3 V and 5 V environments.

Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times.

This device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 1.65 V to 5.5 V
- 5 V tolerant outputs for interfacing with 5 V logic
- · High noise immunity
- Complies with JEDEC standard:
- JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8-B/JESD36 (2.7 V to 3.6 V).
- ESD protection:
- HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- ±24 mA output drive (V_{CC} = 3.0 V)
- CMOS low power consumption
- Open drain outputs
- · Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Inputs accept voltages up to 5 V
- Multiple package options
- Specified from -40 °C to +125 °C.



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3. Ordering information

Table 1. Ordering information

Type number	Package				
	Temperature range	Name	Description	Version	
74LVC1G38GW	-40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1	
74LVC1G38GV	-40 °C to +125 °C	SC-74A	plastic surface-mounted package; 5 leads	SOT753	
74LVC1G38GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886	
74LVC1G38GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	SOT1115	
74LVC1G38GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202	
74LVC1G38GX	-40 °C to +125 °C	X2SON5	plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 × 0.8 × 0.32 mm	SOT1226-3	

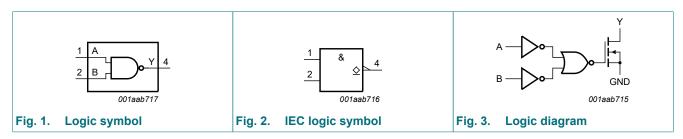
4. Marking

Table 2. Marking

Type number	Marking code[1]
74LVC1G38GW	YB
74LVC1G38GV	YB
74LVC1G38GM	YB
74LVC1G38GN	YB
74LVC1G38GS	YB
74LVC1G38GX	YB

^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram

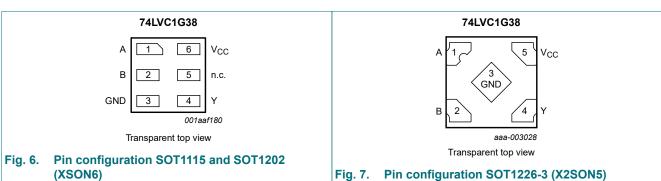


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6. Pinning information

6.1. Pinning





6.2. Pin description

Table 3. Pin description

Symbol	Pin	Pin						
	TSSOP5 and X2SON5	XSON6						
Α	1	1	data input					
В	2	2	data input					
GND	3	3	ground (0 V)					
Υ	4	4	data output					
n.c.	-	5	not connected					
V _{CC}	5	6	supply voltage					

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7. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level; Z = high-impedance OFF state

Input	Output	
A	В	Υ
L	L	Z
L	Н	Z
Н	L	Z
Н	Н	L

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage		-0.5	+6.5	V	
I _{IK}	input clamping current	V _I < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+6.5	V
I _{OK}	output clamping current	V _O > V _{CC} or V _O < 0 V		-	±50	mA
Vo	output voltage	Active mode	[1]	-0.5	+6.5	V
		Power-down mode; V _{CC} = 0 V	[1]	-0.5	+6.5	V
Io	output current	$V_O = 0 V \text{ to } V_{CC}$		-	±50	mA
I _{CC}	supply current			-	100	mA
I _{GND}	ground current			-100	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C	[2]	-	250	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^[2] For SOT353-1 (TSSOP5) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

For SOT753 (SC-74A) package: P_{tot} derates linearly with 3.8 mW/K above 85 $^{\circ}\text{C}.$

For SOT886 (XSON6) package: Ptot derates linearly with 3.3 mW/K above 74 °C.

For SOT1115 (XSON6) package: Ptot derates linearly with 3.2 mW/K above 71 °C.

For SOT1202 (XSON6) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

For SOT1226-3 (X2SON5) package: P_{tot} derates linearly with 3.0 mW/K above 67 °C.

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9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CC}	supply voltage		1.65	-	5.5	V
VI	input voltage		0	-	5.5	V
Vo	output voltage	Active mode	0	-	5.5	V
		Disable mode; V _{CC} = 1.65 V to 5.5 V	0	-	5.5	V
		Power-down mode; V _{CC} = 0 V	0	-	5.5	V
T _{amb}	ambient temperature		-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 1.65 V to 2.7 V	-	-	20	ns/V
		V _{CC} = 2.7 V to 5.5 V	-	-	10	ns/V

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
T _{amb} = -4	40 °C to +85 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 1.65 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.7	-	-	V
		V _{CC} = 2.7 V to 3.6 V	2.0	-	-	V
		V _{CC} = 4.5 V to 5.5 V	0.7 × V _{CC}	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 1.65 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 2.7 V to 3.6 V	-	-	0.8	V
		V _{CC} = 4.5 V to 5.5 V	-	-	0.3 × V _{CC}	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		I _O = 100 μA; V _{CC} = 1.65 V to 5.5 V	-	-	0.1	V
		I _O = 4 mA; V _{CC} = 1.65 V	-	-	0.45	V
		I _O = 8 mA; V _{CC} = 2.3 V	-	-	0.3	V
		I _O = 12 mA; V _{CC} = 2.7 V	-	-	0.4	V
		I _O = 24 mA; V _{CC} = 3.0 V	-	-	0.55	V
		I _O = 32 mA; V _{CC} = 4.5 V	-	-	0.55	V
I _I	input leakage current	V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V	-	±0.1	±1	μΑ
l _{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	±0.1	±2	μΑ
I _{OFF}	power-off leakage current	V _I or V _O = 5.5 V; V _{CC} = 0 V	-	±0.1	±2	μΑ
I _{CC}	supply current	$V_I = 5.5 \text{ V or GND}; V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}; I_O = 0 \text{ A}$	-	0.1	4	μΑ
ΔI _{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A};$ $V_{CC} = 2.3 \text{ V to } 5.5 \text{ V}; \text{ per pin}$	-	5	500	μΑ
Cı	input capacitance		-	2.5	-	рF

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
T _{amb} = -4	40 °C to +125 °C				-	
V _{IH}	HIGH-level input voltage	V _{CC} = 1.65 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.7	-	-	V
		V _{CC} = 2.7 V to 3.6 V	2.0	-	-	V
		V _{CC} = 4.5 V to 5.5 V	0.7 × V _{CC}	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 1.65 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 2.7 V to 3.6 V	-	-	0.8	V
		V _{CC} = 4.5 V to 5.5 V	-	-	0.3 × V _{CC}	V
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		I _O = 100 μA; V _{CC} = 1.65 V to 5.5 V	-	-	0.1	V
		I _O = 4 mA; V _{CC} = 1.65 V	-	-	0.70	V
		I _O = 8 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 12 mA; V _{CC} = 2.7 V	-	-	0.60	V
		I _O = 24 mA; V _{CC} = 3.0 V	-	-	0.80	V
		I _O = 32 mA; V _{CC} = 4.5 V	-	-	0.80	V
l _l	input leakage current	V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V	-	-	±1	μΑ
l _{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±2	μΑ
I _{OFF}	power-off leakage current	V_{I} or $V_{O} = 5.5 \text{ V}$; $V_{CC} = 0 \text{ V}$	-	-	±2	μΑ
I _{CC}	supply current	$V_I = 5.5 \text{ V or GND}; V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}; I_O = 0 \text{ A}$	-	-	4	μΑ
ΔI _{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A};$ $V_{CC} = 2.3 \text{ V} \text{ to } 5.5 \text{ V}; \text{ per pin}$	-	-	500	μΑ

^[1] All typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.

2-input NAND gate; open drain

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). For test circuit see Fig. 9.

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to	Unit	
			Min	Typ[1]	Max	Min	Max	
t _{pd}	propagation delay	A, B to Y; see <u>Fig. 8</u> [2]						
		V _{CC} = 1.65 V to 1.95 V	1.0	3.0	10.0	1.0	12.5	ns
		V _{CC} = 2.3 V to 2.7 V	0.5	1.8	6.0	0.5	7.5	ns
		V _{CC} = 2.7 V	0.5	2.5	5.0	0.5	6.5	ns
		V _{CC} = 3.0 V to 3.6 V	0.5	2.3	4.5	0.5	5.7	ns
		V _{CC} = 4.5 V to 5.5 V	0.5	1.5	3.9	0.5	4.9	ns
C _{PD}	power dissipation capacitance	V_{CC} = 3.3 V; [3] V_I = GND to V_{CC}	-	6	-	-	-	pF

- Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.8 V, 2.5 V, 2.7 V, 3.3 V and 5.0 V respectively.
- t_{pd} is the same as t_{PZL} and t_{PLZ} . C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz;

 f_o = output frequency in MHz;

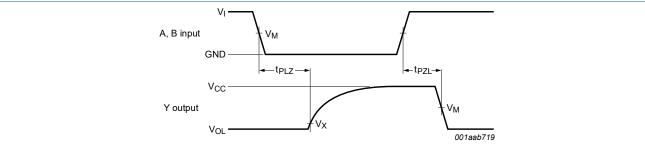
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs.}$

11.1. Waveforms and test circuit



Measurement points are given in Table 9.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

The input (A, B) to output (Y) propagation delays

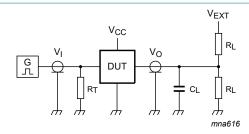
Table 9. Measurement points

Supply voltage	Input	Output				
V _{CC}	V _M	V _M	V _X			
1.65 V to 1.95 V	0.5 x V _{CC}	0.5 x V _{CC}	V _{OL} + 0.15 V			
2.3 V to 2.7 V	0.5 x V _{CC}	0.5 x V _{CC}	V _{OL} + 0.15 V			
2.7 V	1.5 V	1.5 V	V _{OL} + 0.3 V			
3.0 V to 3.6 V	1.5 V	1.5 V	V _{OL} + 0.3 V			
4.5 V to 5.5 V	0.5 x V _{CC}	0.5 x V _{CC}	V _{OL} + 0.3 V			

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Test data is given in <u>Table 10</u>.

Definitions for test circuit:

 R_L = Load resistance.

 $\ensuremath{C_L}$ = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig. 9. Test circuit for measuring switching times

Table 10. Test data

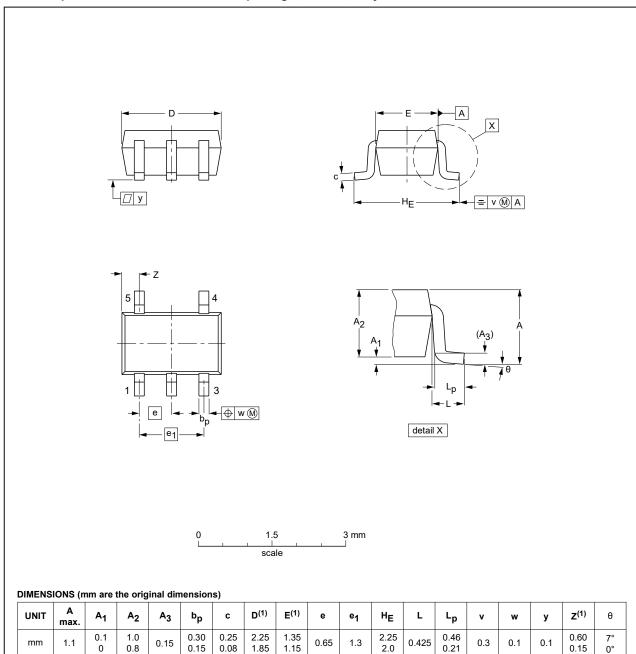
Supply voltage	Input	Input		Load		
V _{CC}	V _I	V _I t _r , t _f C		R _L	t _{PZL} , t _{PLZ}	
1.65 V to 1.95 V	V _{CC}	≤ 2.0 ns	30 pF	1 kΩ	V _{CC}	
2.3 V to 2.7 V	V _{CC}	≤ 2.0 ns	30 pF	500 Ω	V _{CC}	
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	V _{CC}	
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	V _{CC}	
4.5 V to 5.5 V	V _{CC}	V _{CC} ≤ 2.5 ns		500 Ω	V _{CC}	

2-input NAND gate; open drain

12. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1



U	NIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	HE	L	Lp	٧	w	у	Z ⁽¹⁾	θ
r	nm	1.1	0.1 0	1.0 0.8	0.15	0.30 0.15	0.25 0.08	2.25 1.85	1.35 1.15	0.65	1.3	2.25 2.0	0.425	0.46 0.21	0.3	0.1	0.1	0.60 0.15	7° 0°

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES			EUROPEAN	ISSUE DATE	
	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT353-1		MO-203	SC-88A			-00-09-01 03-02-19

Fig. 10. Package outline SOT353-1 (TSSOP5)

2-input NAND gate; open drain

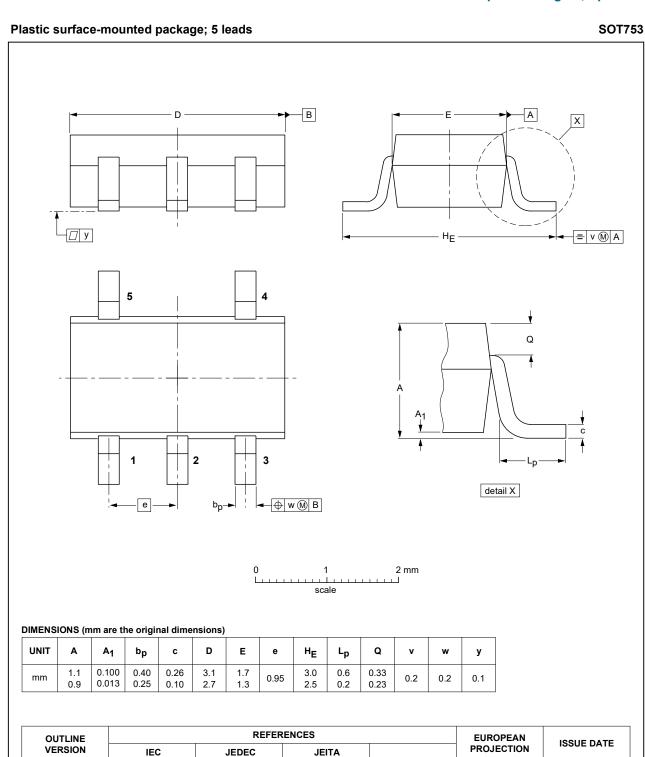


Fig. 11. Package outline SOT753 (SC-74A)

SOT753

SC-74A

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06-03-16

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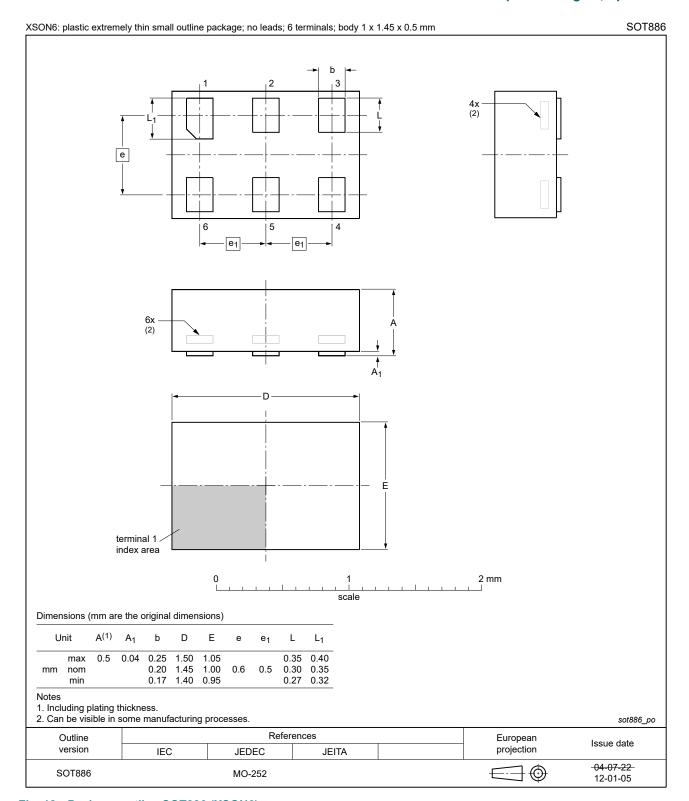


Fig. 12. Package outline SOT886 (XSON6)

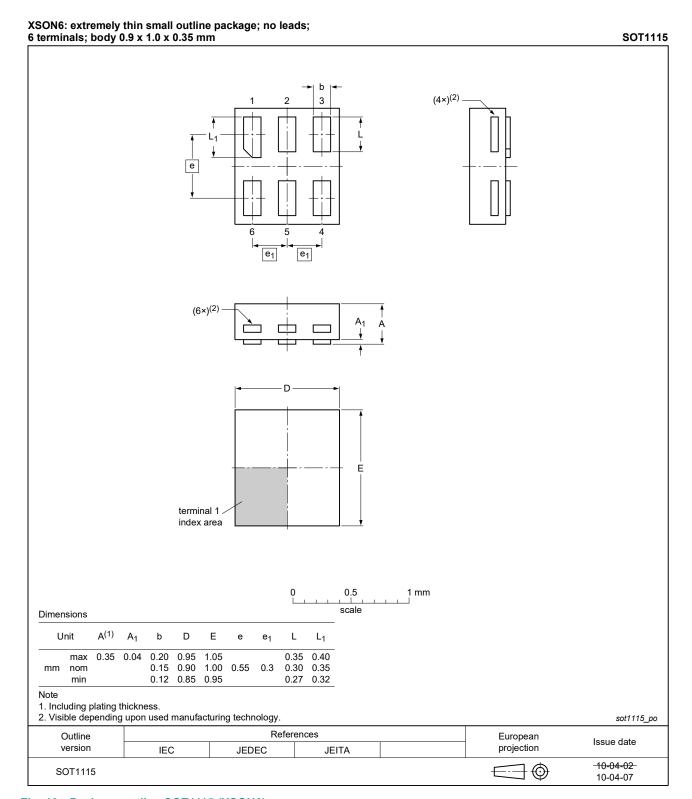


Fig. 13. Package outline SOT1115 (XSON6)

2-input NAND gate; open drain

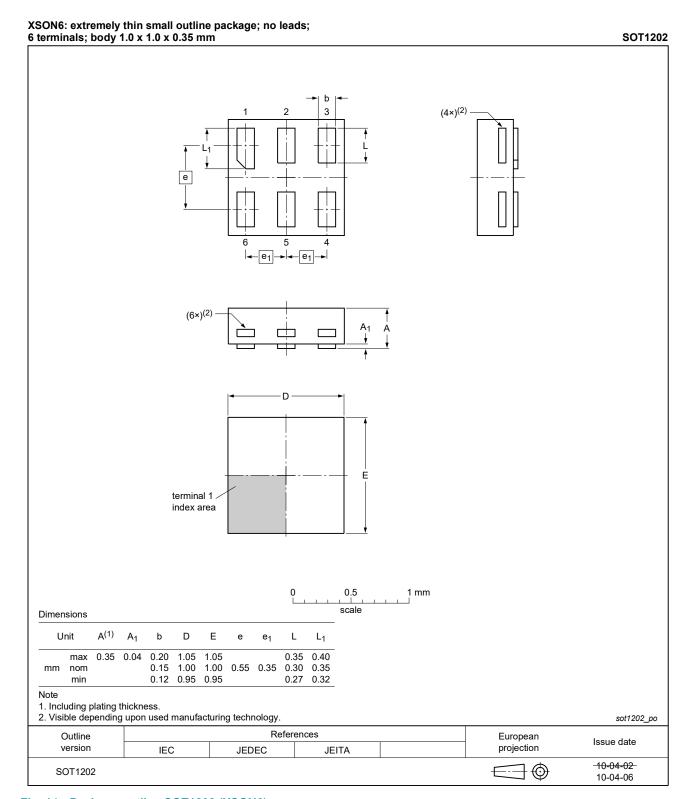


Fig. 14. Package outline SOT1202 (XSON6)

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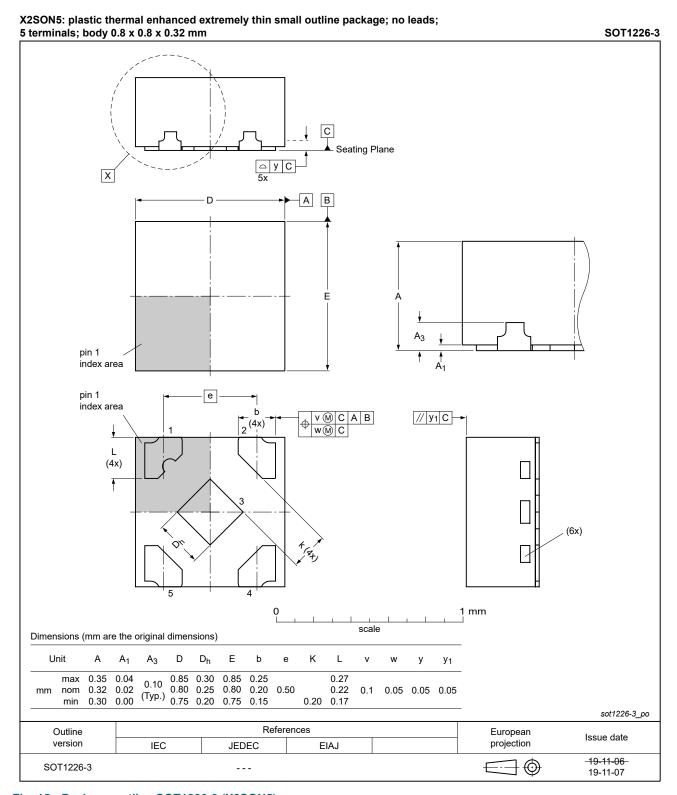


Fig. 15. Package outline SOT1226-3 (X2SON5)

2-input NAND gate; open drain

13. Abbreviations

Table 11. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74LVC1G38 v.9	20210518	Product data sheet	-	74LVC1G38 v.8	
Modifications:	Type number 74LSection 1 update	N5) package changed to SOT1226 VC1G38GF (SOT891/XSON6) rend. d. power dissipation and derating val	noved.) .	
74LVC1G38 v.8	20161207	Product data sheet	-	74LVC1G38 v.7	
Modifications:	<u>Table 7</u> : The maximum limits for leakage current and supply current have changed.				
74LVC1G38 v.7	20121004	Product data sheet	-	74LVC1G38 v.6	
Modifications:	Pin configuration SOT1226 (Fig. 7) modified.				
74LVC1G38 v.6	20120702	Product data sheet	-	74LVC1G38 v.5	
Modifications:	• •	per 74LVC1G38GX (SOT1226) drawing of SOT886 (<u>Fig. 12</u>) modifi	ed.		
74LVC1G38 v.5	20111206	Product data sheet	-	74LVC1G38 v.4	
Modifications:	Legal pages upda	ated.			
74LVC1G38 v.4	20101005	Product data sheet	-	74LVC1G38 v.3	
74LVC1G38 v.3	20070827	Product data sheet	-	74LVC1G38 v.2	
74LVC1G38 v.2	20060913	Product data sheet	-	74LVC1G38 v.1	
74LVC1G38 v.1	20041018	Product data sheet	-	-	

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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2-input NAND gate; open drain

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